<https://www.aau.edu.jo/en/academics/faculty-arts-and-sciences/department-basic-sciences-and-humanities>

Date: 15/9/2022

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| RASHAD IBRAHIM BADRAN |

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| **Personal information** |
|  | Title: Faculty Member |
|  | Academic Rank: Professor of Physics |
|  | Date & Place of Birth: 1955-Iraq |
|  | Nationality: Jordanian |
|  | Address: Jubaiha- next to Tuleen pool- Asayel- St. No 118 |
|  | Phone No.: 0795054410 |
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| **Academic qualifications** |
| Degree | Major | Duration(From-To) | University | Country |
| BSc. | Physics | 1973-1978 | Basra | Iraq |
| M.Sc.  | Physics | 1982-1986 | Kuwait University | Kuwait  |
| Ph.D. | Semiconductor Physics | 1987 - 1991 | Nottingham University | UK |
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| **Teaching experience** |
| Duration | Rank | Institution | Department/Faculty | Country |
| 1979 – 1982 | Research and teaching assistant | Basra University | Physics department | Iraq |
| 1982 - 1986 (M.Sc.) | Researcher working in nuclear physics  | University of Kuwait Post-graduate Research Scholarship | Physics department | Kuwait |
| 1986 – 1987 | Research and lecturer assistant | University of Kuwait  | Physics department | Kuwait |
| 1990 - 1991  | Post graduate student Marking undergraduate course work | Nottingham University | Physics department | UK |
| Jan. 1993-Aug-1993 | Part time lecturer | University of Jordan | Physics department | Jordan |
| 1993 –1995 | Assistant Professor |  University of Petra | Faculty of Science | Jordan |
| 1995- 2003  | Assistant Professor | The Hashemite University | Physics department | Jordan |
| 1999- 2001  | Visiting Research Assistant | Dundee, Scotland, UAD | EPI center  |  UK |
| 2003- 2006 | Associate Professor | The Hashemite University  | Physics department | Jordan |
| 2006- 2010  | Associate Professor | King Abdulaziz University | Physics department | Saudi Arabia |
| Sep.2010- Nov. 2010  | Associate Professor | The Hashemite University  | Physics department | Jordan |
| 2011- 2012  | Professor | German-Jordanian University  | School of Natural Resources Engineering and Management | Jordan |
| 2011-2017  | Professor | The Hashemite University  | Physics department | Jordan |
| 2017-2019  | Professor/Dean | The Hashemite University  | Faculty of Science | Jordan |
| 2017-2022 | Professor/Member of board of Trustees | Petra University | Petra University | Jordan |
| 2019-2020 | Professor/Dean | The Hashemite University | Faculty of Science | Jordan |
| 2022-Now | Professor/Member of board of Trustees | Petra University | Petra University | Jordan |

**Publications**

ــــــــــــــــــــــــــــــــــــــــــــــــــــــــــــــــــــــــــــــــــــــــــــــــــــــــــــــــــــــــــــــــــــــــــــــــــــــــــــــــــــــــــــــــــــــــــــــــــــــــــــــــــــــــــــــــــــــــــــــــــــــــــــــــــــــــــــــــــــــــــــــــــــــــــــــــــــــــــــــــــــــــــــــــــــــــــــــــــــ

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| **Journals** |  |  |
| **Author/s**  | **Title** | **Journal** | **Vol./No.** | **Publication Date** |
| R.I. Badran | Analytical solution of phototransport problem under the presence of a small- signal photocurrent based on method of weighted residuals | Results in Physics<https://doi.org/10.1016/j.rinp.2020.103079> | 17, 103079 | 2020 |
| Y. Al-Hadeethi, **R.I. Badran**, A. Umar, S.H. Al-Heniti, B.M. Raffah, and S. Al-Zahrani. | Electrical properties of Ga-doped ZnO nanowires/Si heterojunction diode | Materials Express https://doi.org/10.1166/mex.2020.1725 | 10, 794-801 |  2020 |
| Y. Al-Hadeethi, A .Umar, S.H. Al-Heniti, B.M. Raffah, and **R.I. Badran** | ZnO Nanowalls/Si Substrate Heterojunction Assembly: Morphological, Optical and Electrical Properties. | Journal of Nanoelectronics and Optoelectronics <https://doi.org/10.1166/jno.2020.2786> | 5, 586-591 |  2020 |
| **R.I. Badran**, Y. Al-Hadeethi, A. Umar, S.H. Al-Heniti, B. M. Raffah, S. Ansari, and A. Jilani. | Temperature-dependent heterojunction device characteristics of n-ZnO nanorods/p-Si substrate assembly | Materials Express <https://doi.org/10.1166/mex.2020.1595> | 10, 29-36. |  2020 |
| Y. Al-Hadeethi, **R.I. Badran**, A .Umar, S.H. Al-Heniti, B.M. Raffah, and A.M. Alharbi. |  Growth of n-Ga doped ZnO nanowires interconnected with disks over p-Si substrate and their heterojunction diode application | Materials Expresshttps://doi.org/10.1166/mex.2020.1594 | 10, 21-28 | 2020 |
| H. Algarni, **R. I. Badran**, M. A. Khan, F.J. Hassen, S. H. Kim, and A. Umar. | Fabrication and Temperature Dependent Electrical Characterization of n-ZnO Nanowires/p-Si Substrate Heterojunction Diodes | Journal of Nanoelectronics and OptoelectronicsDOI: 10.1166/jno.2017.2140 | 12, 1162–1166 |  2017 |
| S. H. Kim, **R. I. Badran**, Ahmad Umar | Fabrication of ZnO Nanorods Based p–n Heterojunction Diodes and Their Electrical Behavior with Temperature | Journal of Nanoelectronics and Optoelectronicsdoi:10.1166/jno.2017.2134 | 12, 731–735, | 2017 |
| **R. I. Badran,** A. I. Istaiti, W. N. Mashaqbeh, I. H. Al-Lehyani | 1. Regge Pole Analysis of Elastic Scattering of α Particles by Even Isotopes of Ni Target at Incident Energies Above Coulomb Barrier
 | International Journal ofModern Physics <http://dx.doi.org/10.1142/S0218301315500822> | 24, 1550082-23 | 2015 |
| S. H. Al-Heniti**,** **R. I. Badran** and A. Umar  | 1. Temperature-Dependent Electrical Properties of Sn-Doped ZnO Nanowires
 | Science of Advanced Materials<http://dx.doi.org/10.1166/sam.2015.2708> | 7, 2684-2691 | 2015 |
|  **R. I. Badran** and D. Al-Masri | 1. Exploring Diffractive Features of Elastic Scattering of 6Li on Different Nuclei at

 Different Energies | Canadian Journal of Physics<http://dx.doi.org/10.1139/cjp-2012-0466> | 91, 355-364 |  2013 |
| A. Umar, M. S. Akhtar, R. I. Badran, M. Abaker, S. H. Kim, A. Al-Hajry, S. Baskoutas | Electrical properties of solution processed p-SnS nanosheet/n-TiO2 heterostructure assembly | Applied Physics Letters <http://dx.doi.org/10.1063/1.4819838> | 103, 101602 | 2013 |
| **R. I. Badran**, A. Umar, S. Alheniti, T. Al-Harbi | 1. Synthesis and characterization of hexagonal zinc oxide nanorods on silicon for the fabrication of p-Si/ n-ZnO heterojunction devices.
 | Journal of Alloys and Compounds [**http://dx.doi.org/10.1016/jallcom.2010.08.048**](http://dx.doi.org/10.1016/jallcom.2010.08.048) | 508, 375-379 | 2010 |
| **R. I. Badran,** F. S. Al-Hazmi, S. Al-Heniti, A. Al-Ghamdi, J. Li and S. Xiong | 1. A study of optical properties of hydrogenated microcrystalline silicon films prepared

by plasma enhanced chemical vapor deposition technique at different conditions of excited power and pressure.  | Vacuum [**http://dx.doi.org/10.1016/j.vacuum.2009.01.009**](http://dx.doi.org/10.1016/j.vacuum.2009.01.009) | 83, 1023-1030 | 2009 |
| **R. I. Badran** | 1. Analysis of field
2. Dependent steady-statephotocarrier measurements for
3. polymorphous and microcrystalline semiconductors
 | Journal MaterialsScience: Materials inElectronics [**http://dx.doi.org/10.1007/s10854-006-9047-x**](http://dx.doi.org/10.1007/s10854-006-9047-x) | 18, 4, 405-414 | 2007 |
| **R. I. Badran** and N. Al-Awwad. | On electronic properties from the application of field dependence SSPG approaches to polymorphous and microcrystalline silicon semiconductors. | Journal of Optoelectronics and Advanced Materials[**http://dx.doi.org/10. 27497/35400015695977.0280**](http://dx.doi.org/10.%2027497/35400015695977.0280) | 8, 4 | 2006 |
| **R. I. Badran**, C. Main and S. Reynolds. | Analysis and modeling of generation- recombination noise in amorphous semiconductors | Thin Solid Films[**http://dx.doi.org/10.1016/S0040-6090(02)01159-8**](http://dx.doi.org/10.1016/S0040-6090%2802%2901159-8) | **427** , 133-36 | 2003 |
| **R. I. Badran**, D. J. Parker and I. M. Naqib | Complete and incompletefusion in reactions of 7Li + 56Fe at E (7Li) = 50 and 68 MeV from analysis of recoil range light particle measurements | European Physical Journal [**http://dx.doi.org/10.1007/s100500170009**](http://dx.doi.org/10.1007/s100500170009) | **12**, 317-325 | 2001 |
| C. Main, S. Reynolds, **R. I. Badran** and J. M. Marshall | High resolution density of states spectroscopy in semiconductors by exact post-transit current analysis. | Journal of Applied Physics[**http://dx.doi.org/10.1063/1.373797**](http://dx.doi.org/10.1063/1.373797) | 88,1190-1192 | 2000 |
| **R. I. Badran**, I M Naqib, D J Parker and J Asher | Strong absorption formalism applied to the direct transfer reaction 56Fe (7Li, 4He) 59Co\* leading to continuum states | Journal of Physics : Nuclear and Particle Physics[**http://iopscience.iop.org/0954-3899/22/10/008**](http://iopscience.iop.org/0954-3899/22/10/008) | 22, 1441 | 1996 |
| **R. I. Badran**, S. Jamila, P. J. Kirk, C. A. Bates and J. L. Dunn. | First andsecond-order reductionfactors for E ⊗ e Jahn-Teller system | Journal of Physics: Condensed Matter[**http://dx.doi.org/10.1088/0953-8984/5/10/008**](http://dx.doi.org/10.1088/0953-8984/5/10/008) | 5, 1505-1816 | 1993 |
| **R. I. Badran**, C. A. Bates | An Analysis of the strongly coupled E ⊗ e Jahn-Teller system: Anisotropy and inversion splitting | Journal of Physics: Condensed Matter[**http://dx.doi.org/10.1088/0953-8984/3/33/012**](http://dx.doi.org/10.1088/0953-8984/3/33/012) | 3, 6329-6343 | 1991 |
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| **Conferences** |  |
| Author/s(In Order) | Title | Conference | Country | Date |
| **R. I. Badran** and R. Bruggemann | Exploitation of the electric-field dependence of photocarrier properties by application of the steady-state photocarrier grating technique | 19th European Photovoltaic Solar EnergyConference and Exhibition | Paris/Jordan | June 7-11, 2004 |
| **R. I. Badran** | Dynamical Jahn-Teller effects in the excited 3T1 and 3T2 states of V3+ ion in III-V semiconductors. | Third Conference on Physics of Condensed Matter | Jordan  | 17-21 April (1994) |
| **R. I. Badran** | Further Investigation on the transfer reaction 7Li on 56 Fe at 50MeV incident energy | First International Conference of Mathematics and Nuclear Physics | Cairo/ Egypt  | April 2003 |
| C. Main, S. Reynolds, **R. I. Badran** | Generation-recombination noise on amorphous semiconductors | CHELSEA Amorphous and Organic Semiconductors Meeting, Imperial College Science, Technology and Medicine | London/UK | April 5-6 (2001) |
| C. Main, S. Reynolds, **R. I. Badran**, and J. M. Marshall | Improved high-resolution post-transit spectroscopy for determining the density of states in amorphous semiconductors | IOP European Workshop on Novel Photovoltaic Materials | University of Bath/UK | July (2000) |
| **R. I. Badran** | Further analysis on the interband transitions of V3+ ions in GaAs and InP hosts under uniaxial stresses | The First Conference on Physics and Condensed Matter | Jordan | May (1997) |
| **Memberships OF Scientific and professional societies** |
| **I. King Abdulaziz University:**Member and consultant of the academic accreditation committee, 2009-2010**II. The Hashemite University:**1. Member, Faculty of Science and arts Council, 1995-1996.2. Member, Deposit Fund Committee, The Hashemite University, 1998-1999.3. Member, Faculty of Science Library Committee, 1995- 2005.4. Member, Faculty of science and Arts Social Committee, 1999-2000.5. Member, Faculty of science and Arts Council, 1999-20006. Member, Faculty of Science and Arts Cultural Committee, 1998-1999.7. Member, Faculty of science and Arts Checking Marks Committee, 1997-1998.8. Member of various Departmental and Faculty Committees including examination and scheduling committee, graduate studies and the scientific research committee, social committee, checking marks committee, library committee, 1995-2003.9. Member, Faculty of Science and Arts, Cultural Committee 2003-2004.10. Member of Graduate Studies committee, Department of Physics, 2005-200611. Member, Faculty of Science Cultural Committee, 2010-201112. Member of Committee, Center of studies, Consultations and Community Service, 2010- 201113. Member of Hashemite University Council, Representative of Faculty of Science, 2010- 2011.14. Member of Graduate Studies and Scientific Research Committee, Department of Physics, 2012-201415. Member of the Academic Developing Committee in Hashemite University, 2015- 2016.16. Member of Curriculum Committee in Hashemite University, 2017/2018-2019/2020.17. Member of Decision- Making Committee for Students Affairs in Hashemite University, 2017/2018-2018/2019.18. Member of Students Marks Committee in Hashemite University, 2017/2018- 2018/2019. Head of this committee 2019/202019. Member of Disciplinary Appeals Board of Member of Academic Staff in Hashemite University, 2016/2017, 2017/2018 and 2019/202020. Chairperson of Disciplinary Appeals Board of Employees in Hashemite University, 2016/2017, 2017/2018.21. Head of team working for international accreditation (ABET) for the programs of Faculty of Science.**III. Petra Private University (previously Jordan University for Women):**-Member, Faculty of Science Council, 1993 - 1995.-Member, Faculty of Science Social Committee, 1994 - 1995.-Board of Trustees Member of Petra University, Nov. 2017- 2022-Board of Trustees Member of Petra University, Nov. 2022- Now**IV. Members of Editorial board*** + 1. **“Jordan Journal of Physics” (**Editorial Board Member**)**

<https://www.scimagojr.com/journalsearch.php?q=21100871853&tip=sid&clean=0>* + 1. **"Journal of Nanoelectronics and Optoelectronics"** (***Associate Editor***)

 <http://www.aspbs.com/jno/jno_editorial.htm> (American Scientific Publishing**)**3. ***Science of Advanced Materials*** (Editorial Board Member) [**http://www.aspbs.com/sam/**](http://www.aspbs.com/sam/)**(**American Scientific Publishing**)**4.  **Sensor Letters** (Editorial Board Member)[**http://www.aspbs.com/sensorlett/editorial\_sensorlett.htm**](http://www.aspbs.com/sensorlett/editorial_sensorlett.htm) (American Scientific Publishers, USA**)****Membership:**-Graduate member of the Institute of Physics (IOP)-London.-Member of the Jordanian scientific research society, Amman, Jordan.- Member of the Hashemite University Personnel Club. |
| **university Committees (AAU)**Member, Dean Council, 2022 – NowMember, Faculty of Arts and Sciences, Scientific research Committee 2022-NowMember, Faculty of Arts and Sciences, Curriculum Committee 2022-Now |

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| **Workshops Attended** |
| 1. Regional workshop on Nanotechnology, organized by Sultan Qaboos University, between 12th- 14th January 2008 at Muscat, Oman. 2. First Yarmouk school for computational condensed matter and Nano systems, organized by center for theoretical and applied physical sciences, Yarmouk University, between 31st Oct.-Nov. 4th , 2010, Irbid, Jordan.3. Training Course in UNIX systems organized by AST Computer Company, Jordan held at its main office in Amman, Feb. 1-5, 2000.4. IT Premier workshop on Basic Web technology skills for courseware development held at Yarmouk University, Irbid, Jordan, Feb. 11-15, 2001. This workshop is collaboratively organized by UNESCO-Cario Office, Yarmouk University and cosponsored by UNDP. 5. IT Premier workshop on Basic Web technology skills for courseware development held at The Hashemite University, Zarqa, Jordan, Dec. 1 to Feb. 2, 2003 |
| **Seminars**  |
| 1. Nanocrystalline semiconductors: A new era of Photovoltaic applications, April 24, 2009, Physics Department, King Abdulaziz University, Jeddah, KSA.2. A comprehensive study of nanocrystalline silicon semiconductors, March 19, 2008, Physics Department, King Abdulaziz University, Jeddah, KSA.3. Theoretical work on electronic properties of microcrystalline semiconductors, Nov. 1, 2006, Physics Department, King Abdulaziz University, Jeddah, KSA4. Generation-Recombination Noise in Amorphous Semiconductors, July 27, 2003 GRECO, Physics Department, Oldenburg University, Germany.5. Incomplete Fusion of 7Li + 56Fe at Incident Energies of 50 and 68 MeV, April 4, 2003, Physics Department, The Hashemite University.6. Perturbation Theory as Applied to Complex Systems, Sept. 1994, Physics Department, University of Applied Sciences, Jordan.7. Jahn-Teller Effects in Crystalline Semiconductors, May 15 1995, Physics Department, Mu'ta University, Jordan.8. Some Aspects of Vibronic Interactions in Complex Molecules and Crystalline Solids. Jan, 9, 1993, Physics department, Jordan University.9. Theoretical Studies of Heavy Ions at Intermediate Energies using The Diffraction Model, Oct. 11, 1986, Group of Nuclear Physics, Kuwait Institute of Scientific Research, Kuwait. |
| **Research interests** |
| 1. The studies of photoelectrical and optical properties of amorphous and nanocrystalline thin films semiconductor using the Steady-State Photocarrier Grating (SSPG) technique and sepectrophotometry. This includes a specific study of the minority carrier properties and the optical constants. The experimental studies are accompanied with the implementation of different theoretical approaches. Furthermore, the study of electrical properties of ZnO nanowires, nanorods and nanosheets fabricated as heterojunction diodes, is another interest. 2. The study of electrical properties of semiconductors, via the transient photoconductivity (TPC) and the modulated photoconductivity (MPC) on nanocrystlline and amorphous semiconductors samples is conducted where the numerical methods of Fourier and Laplace transforms are used to determine the density of states in the mobility gap. 3. The analysis of noise in semiconductor devices is also conducted. The analysis of generation-recombination noise in amorphous semiconductor devices based on multipletrapping-state regime using the equivalent circuit model of Chaplin is the main theme of this work. The spectral noise is calculated and compared to the theoretical results of other models. Monte-Carlo simulation programs are also developed to calculate the spectral noise and these results are compared to the above-mentioned theoretical results and experimental data. 4. Research work in nuclear physics involving heavy ion collisions is of one of my interests. The first part of this research deals with the analysis of elastic scattering of heavy nuclei at low energies. While the second part involves the incomplete fusion, and transfer reactions of different heavy nuclei at various energies. Different numerical models are developed and employed in this theoretical work. 5. The theoretical studies of the transition metal ions as impurities in the crystalline group III-V semiconductors are the main theme of my research work in solid state physics. The analytical method of unitary transformation followed by energy minimization is used to study the E e Jahn-Teller system in the strong coupling limit. The inversion splitting and reduction factors are obtained analytically. The Schrödinger equation is solved for this complex system, and the perturbation theory is used. This work also involves modeling the transition metal ion V3+ as an impurity in the GaAs, GaP, and InP semiconductors. In particular, the analysis of the structure of the zero-phonon lines of transitions within V3+ ions, in the above-mentioned hosts, under the effects of spinorbit coupling, uniaxial stress and external magnetic field which are accompanied by Jahn-Teller effects, are studied. |
| **Languages** |
| Arabic: NativeEnglish: Very good at reading, writing and speaking.French: Fair at reading, writing and speaking. |
| **Other Community activities** |
| 1. Served as evaluator for different applications of promotions to rank of associate professor and professor of physics at different regional Universities2. Served as a project evaluator at Mayar International School-Amman, Jordan for projects of students presented at "Science Fair", held on May 2012, and on May 2013.3. Nominee by Saudi Physical Society in collaboration with ARAMCO-SA and King Fahd University for petroleum and minerals (KFUPM) to contribute in summer teaching program to teach special oriented topics in physics for intellectual students (graduate and postgraduate levels) and physics teachers in SA schools and teaching assistants at Saudi Universities at summer scientific school held at KFUPM, Dhahran, 2007-2008. 4. Served as member of the qualifying exam committee, ministry of higher education, for the academic year 2005-2006.5. Served as member on the organizing committee for the cultural and scientific day held at the Hashemite University held on April 27, 2004. 6. Served as member on the organizing committee of the seventh Petra School of Physics held by the Jordan Council for scientific research on Sept., 17-22, 2000 at Jordan University.7. Served as member on the organizing committee for the elections of the students Council at the Hashemite University held on April 18, 1999. 8. Attending meetings of the society for friends of scientific research as a member of this society, Amman, Jordan, 2001/2005. |
| **Awards received** |
| - Research Awards from Hashemite University, 2012, 2013, 2014, 2015. 2016 and 2017 - Our Accepted article in "Vacuum" journal has been chosen by Elsevier among the top 25  articles in the period between April to June 2009 - Distinguished Research Award from King Abdulaziz University, Nov. 2009 - Distinguished Research Award from King Abdulaziz University, Dec. 2010 - Part-time teaching assistantship from Physics Department, University of Nottingham  (Oct. 1990 - June 1991). - Kuwait University Academic Assistantship (Sept. 1982- Mar. 1986). |
| **Graduate Students’ Supervision** |
| 1. Supervising Anwar Issa, MSc student at HU, in her research work: Analytical solutions of nonlinear differential equations for problems in semiconductor physics using approximation methods (2016)2. Supervising Wafa Mashaqbeh, MSc Student at HU, in her research work: Analysis of a set heavy-ion of nuclear reactions at different energies and above Coulomb barrier based on Regge pole and strong absorption models (2015).3. Supervising Amani Estaiti, MSc Student at HU, in her research work: Regge pole analysis of elastic scattering of α-particles on different target nuclei at incident energies above Coulomb barrier (2014).4. Supervising Dana Al-Masry, MSc Student at HU, in her research work: Numerical modeling and analysis of nuclear reactions of heavy ions at different energies using parameterization models (2012).5. Supervising Huda Al-Amodi, MSc Student at KAU-Saudi Arabia, in her research work: Analysis of optical and photoelectronic properties of nanocrystalline materials (2011).6. Supervising Hind Badahdah, MSc Student at KAU-Saudi Arabia, in her research work: Analysis of angular distribution of elastic scattering reactions for heavy nuclear ions based on the diffraction model (June, 2009).7. Supervising Reem Al-Khalidi, MSc. Student at HU, in her research work: “A theoretical study of the elastic scattering of nuclear heavy ions by using the strong absorption model”, (July 2006).8. Supervising Noor Al-Awaad, MSc. Student at HU, in her research work: “Theoretical analysis of the electronic properties of microcrystalline and amorphous semiconductors”, (May 2005). |
| **References** |
| 1-Prof. Ahmad UmarCollaborative Research Centre for Sensors and Electronic Devices (CRCSED), Advanced Materials and Nano-Engineering Laboratory (AMNEL), Centre for Advanced Materials and Nano-Engineering (AMNEL), Najran University, P. O. Box 1988, Najran-11001, Kingdom of Saudi Arabiae-mail: ahmadumar786@gmail.com2-Prof. Ali Al-KarmiVice President for scientific Colleges and Centers,The Hashemite University, Zarqa, Jordan.Tel.:+962(5)3903333Fax:+962(5)3826613e-mail: karmi@hu.edu.jo 3- Prof. Abdallah QteishPhysics Department,Yarmouk University, Irbid, JordanTel.:+962777485698e-mail: aqteish@yu.edu.jo4- Dr Rudi BrueggemannInstitut für Physik, Carl von Ossietzky Universität Oldenburg,D-26111 Oldenburg, Germany,e-mail: rudi.brueggemann@uni-oldenburg.de |